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Short communication

Detecting Lyme disease using antibody-functionalized single-walled carbon nanotube transistors

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ABSTRACT

We examined the potential of antibody-functionalized single-walled carbon nanotube (SWNT) field-effect transistors (FETs) to use as a fast and accurate sensor for a Lyme disease antigen. Biosensors were fabricated on oxidized silicon wafers using chemical vapor deposition grown carbon nanotubes that were functionalized using diazonium salts. Attachment of *Borrelia burgdorferi* (Lyme) flagellar antibodies to the nanotubes was verified by atomic force microscopy and electronic measurements. A reproducible shift in the turn-off voltage of the semiconducting SWNT FETs was seen upon incubation with *B. burgdorferi* flagellar antigen, indicative of the nanotube FET being locally gated by the residues of flagellar protein bound to the antibody. This sensor effectively detected antigen in buffer at concentrations as low as 1 ng/ml, and the response varied strongly over a concentration range coinciding with levels of clinical interest. Generalizable binding chemistry gives this biosensing platform the potential to be expanded to monitor other relevant antigens, enabling a multiple vector sensor for Lyme disease. The speed and sensitivity of this biosensor make it an ideal candidate for development as a medical diagnostic test.

1. Introduction

Lyme disease is a tick-borne illness caused by the bacteria *Borrelia burgdorferi*, generating at least 30,000 new cases in the United States each year, although there are likely many more cases that go undetected or misdiagnosed due to generality of symptoms (Centers for Disease Control and Prevention, 2011). Of the patients diagnosed with Lyme disease, many are originally misdiagnosed due to the general symptoms of the disease (Williams et al., 1990), inconsistent disease presentation in patients (Aguerorosenfeld et al., 1993), and lack of sensitive testing available for early stages of the infection (Bakken et al., 1997). Late detection of Lyme disease can result in further complications including arthritis and permanent neurological disorders (Marques, 2008). Diagnosis of Lyme disease is severely hindered by the lack of reliable diagnostic tools despite its importance to treatment success (Murray and Shapiro, 2010; O'Connell, 2010). A reliable and rapid laboratory diagnostic tool is crucial for reducing the number of misdiagnosed patients and for investigating appropriate treatment protocols for chronic Lyme disease.

In recent years, great progress has been made in the field of carbon nanotube field effect transistor (CNT FET)-based biosensors (Allen et al., 2007). Benefits of nanotube-based sensors include the speed and reliability obtained from performing multiple assays in parallel (Chikkaveeraiah et al., 2009). Protein-functionalized nanotube-based FETs are of great research and clinical interest for several reasons. Their nanometer size is comparable to the size of many biomolecules of interest, suggesting a unique biocompatible platform (Harrison and Atala, 2007; Lerner et al., 2011; Sudibya et al., 2009). Additionally, since every atom of a carbon nanotube is located on its surface, in direct contact with the environment, they are a clear choice for direct environmental sensing. Commercially available assays for Lyme-specific antigens in urine and cerebrospinal fluid have a limit of detection of 12–15 ng/mL (Shah et al., 2004). We hypothesized that an antibody-functionalized SWNT FET immunosensor would be able to detect the small amount of Lyme antigen that is present in bodily fluids at very early stages of Borrelia infection (Harris and Stephens, 1995) since protein-functionalized nano-enabled sensors have demonstrated very low detection limits, on the order of fM (Duan et al., 2012; Lerner et al., 2012a). Direct detection of the antigen provides

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earlier test results because it eliminates the delay required for the immune system to produce sufficient quantities of antibodies to be detected via Western Blot or ELISA, which can improve patient prognosis (Ma et al., 1992). Here we demonstrate that antibody-functionalized SWNT FET devices are effective biosensors for rapidly detecting Lyme flagellar antigen at clinically relevant concentrations, as low as 1 ng/ml, with negligible response to negative-control proteins and to pure buffer solution.

2. Materials and methods

2.1. Device fabrication

Carbon nanotube transistors were fabricated using previously described methods (Goldsmith et al., 2011; Khamis et al., 2011). Briefly, a solution of iron (III) nitrate dissolved in isopropanol was spin coated onto a p^{2+} doped Si/SiO_2 wafer to give an iron catalyst layer. Single-walled carbon nanotubes were grown by catalytic chemical vapor deposition (CVD) with methane (2500 sccm) as the carbon source in a background of forming gas (600 sccm Ar, 320 sccm H_2) at 900 °C for 2 min. Following the growth, an optimized bilayer photolithography process using PMGI and Shipley 1813 (Khamis et al., 2011) was used to pattern source and drain electrodes with 2.5 μm channel length that were then metallized (3 nm Ti/40 nm Pd) using thermal evaporation. The doped silicon substrate served as a global backgate to complete the three terminal field-effect transistor geometry. Devices were individually characterized by sweeping the back gate voltage from −10 V to 10 V while holding the bias voltage fixed at 100 mV. Approximately 80 high quality semiconducting SWNT devices with ON/OFF ratios >1000 were selected to use in experiments.

2.2. Protein functionalization

Monoclonal Lyme antibodies specific for *B. Burgdorferi* flagellar antigen (p41) were obtained commercially (antibodies-online.com). Histidine-tagged Lyme antigen containing the p41 flagellar immunodominant region (also known as flagellin) was obtained from ProSpec. Antigen was diluted with Tris–HCl buffer (pH 7.5), aliquoted to several concentrations and stored at 4 °C. Antibodies were aliquoted at a concentration of 1 μg/ml in Tris–HCl buffer and stored at −20 °C.

Nanotube functionalization followed previously documented procedures (Goldsmith et al., 2011; Lerner et al., 2012a) adapted from (Strano et al., 2003) (see Fig. 1). Carbon nanotubes were functionalized using diazonium salts synthesized according to a published recipe (Saby et al., 1997). Samples were immersed in a solution of 4-carboxybenzene diazonium tetrafluoroborate at a concentration of 2.5 mg/1 mL deionized (DI) water for 1 h at 40 °C to create sp^3 hybridization sites ending in carboxylic acid groups, then rinsed for 1 min each in acetone, methanol, and deionized water baths. The carboxylic acid groups were then activated with EDC and stabilized with sulfo-NHS at concentrations of 6 mg and 16 mg per 15 mL MES buffer (pH 6.0) respectively for 15 min at room temperature, followed by a DI water rinse. A solution of antibodies at a concentration of 1 μg/mL was pipetted onto the nanotube devices in a humid environment to prevent the solution from evaporating, causing primary amines on the antibody to displace stabilized sulfo-NHS sites over a period of 1 h. The devices were washed thoroughly by rinsing in two DI water baths for 2 min each and dried with gentle (less than 20 psi) nitrogen flow in order to minimize the amount of salts and non-specifically bound proteins on the device.

Antibody-functionalized SWNT-FET devices were similarly exposed to droplets of antigen at a known concentration for 20 min in a humid environment to prevent the droplet from evaporating. Exposure to Lyme flagellar antigen occurred over a sufficiently long time for the proteins to diffuse to the sensor and establish equilibrium between bound and unbound species. This is known to be a critical consideration for detection of biomolecular analytes at pM or lower concentration (Squires et al., 2008). The devices were then washed in two DI water baths for 2 min each to remove non-specifically bound antigen and dried with gentle nitrogen flow. Each device was exposed to only one concentration of antigen in order to avoid contamination of samples, and each concentration of antigen was tested on 5–10 functionalized devices to ensure reproducibility of the results.

3. Results and discussion

In order to verify the validity of the attachment chemistry, Atomic Force Microscopy (AFM) data were gathered on an Asylum AFM in tapping mode followed by both antibody attachment (Fig. 2a) and subsequent exposure to flagellar antigen at a concentration of 400 ng/mL (Fig. 2b). Fig. 2a (Fig. 2b) is an AFM image showing small ball-like features that are associated with bound antibodies (antibody/antigen complexes), with a density ca. 3-5 attachments per micrometer. As is typically found in AFM analysis, the lateral dimension of the features (~50 nm in Fig. 2b) is larger than the molecular size, which is an artifact associated with the finite radius of the AFM tip. The *height* of the features is therefore compared with the expected size of the antibody and antibody/antigen complex. Statistical analysis of the feature heights in Fig. 2a shows that the antibodies are 2.78 nm ± 0.22 nm in size, slightly smaller than expected for a complete IgG. This is likely due to the protein being slightly distorted during the tapping mode AFM in air, as we have reported previously (Johnson et al., 2009; Zhang et al., 2007). After exposure to flagellar antigen, the histogram of feature heights shows new peaks at 4.7 ± 0.6 nm and 6.5 ± 0.4 nm associated with larger antibody/antigen complexes. These are ascribed to binding of one and two antigen proteins, respectively, to a bound antibody, consistent with the fact that the IgG used in the experiments has two binding sites (Talwar and Srivastava, 2006). Each added antigen increases the feature height by ~1.8 nm. There also appears to be an additional minor peak at ~3 nm that represents unreacted antibodies; this peak accounts for ~20% of the total features measured. These data suggest that after exposure to antigen at 400 ng/mL, approximately 80% of the antibodies have bound to at least one antigen, in good agreement with the electronic response data presented in Fig. 3b.

We conducted a control experiment to establish that nanotubes and the nanotube/SiO_2 interface show very low affinity for non-specific binding of the Lyme antigen; details are provided in Supplementary material Fig. S1. When as-prepared nanotube devices were exposed to a high concentration (1 μg/mL) of Lyme antigen, there was minimal non-specific binding to the nanotubes or to the surrounding substrate. We also confirmed that exposure to the Lyme antigen at this concentration had negligible effect on the electronic characteristics of the device. These control experiments provide strong evidence that the biosensor responses described below reflect specific binding of the antigen.

Electronic measurements of the current as a function of the backgate voltage (I–V_g characteristics) for individual NT FET devices were taken following each chemical modification to monitor the effect of chemical functionalization and to confirm attachment of antibodies (Fig. 3a). Parameters of interest included I_{ON}, the ON state current of the device, and V_{TH}, the threshold voltage, where the line tangent to the I–V_g curve intersects the gate voltage axis. A 50–90% drop in I_{ON} as well as a 3–4 V decrease in